

SK8403180L

MOS FET SK8403180L

For Load-switching / For DC-DC Converter

Silicon N-channel MOS FET

- Features
- Low Drain-source On-state Resistance : RDS(on) typ = 6.7 mΩ (VGS = 4.5 V)
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL : Level 1 compliant)
- Marking Symbol : 18
- Packaging

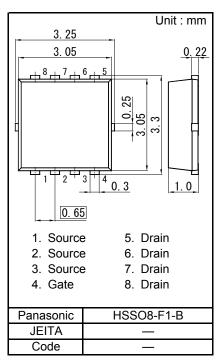
Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

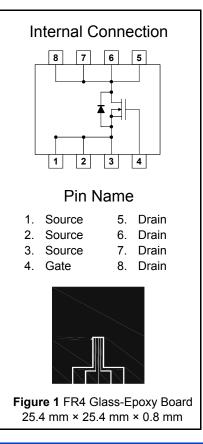
■ Absolute Maximum Ratings Ta = 25 °C								
Parameter			Symbol	Rating	Unit			
Drain to Source Voltage			VDS	30	V			
Gate to Source Voltage			VGS	±20	v			
	Ta = 2	Ta = 25 °C, t = 10 s ^{*1}		17				
Drain Current	Ta = 25 °C, DC ^{*1} Tc = 25 °C		ID	12	А			
				39	~			
	Pulsed	l, Tch < 150 °C ^{*2}		51				
Total Power			PD	2	W			
Dissipation		Tc = 25 °C	FD	19	vv			
Thermal Resistance		Channel to Ambient	Rth(ch-a)	62.5	°C/W			
	ance	Channel to Case	Rth(ch-c)	6.6	0/00			
Channel Temperature			Tch	150				
Operating ambient temperature			Topr	-40 to +85	°C			
Storage Temperature Range			Tstg	-55 to +150				
Avalanche Current (Single pulse) *3		IAR	8.5	А				
Avalanche Energy (Single pulse) *3		EAR	9	mJ				

Note *1 Device mounted on a glass-epoxy board in Figure 1

*2 Pulse test: Ensure that the channel temperature does not exceed 150 °C

*3 VDD = 24 V, VGS = 10 to 0 V, L = 0.1 mH, Tch = 25 °C (initial)







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■ Electrical Characteristics Ta = 25 °C ± 3 °C

Static Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = 1 mA, VGS = 0 V	30			V
Zero Gate Voltage Drain Current	IDSS	VDS = 30 V, VGS = 0 V			10	μA
Gate-source Leakage Current	IGSS	VGS = ±16 V, VDS = 0 V			±10	μA
Gate-source Threshold Voltage	Vth	ID = 1.45 mA, VDS = 10 V	1.3		3	V
Drain-source On-state Resistance	RDS(on)1	ID = 8.5 A, VGS = 10 V		5.1	7.1	mΩ
	RDS(on)2	ID = 8.5 A, VGS = 4.5 V		6.7	9.8	

Dynamic Characteristics

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input Capacitance	Ciss	VDS = 10 V, VGS = 0 V		1 200	1 680	
Output Capacitance	Coss	f = 1 MHz		140	200	pF
Reverse Transfer Capacitance	Crss			100	160	
Turn-on Delay Time ^{*1}	td(on)	VDD = 15 V, VGS = 0 to 10 V		8		20
Rise Time ^{*1}	tr	ID = 8.5 A		6		ns
Turn-off Delay Time ^{*1}	td(off)	VDD = 15 V, VGS = 10 to 0 V		39		20
Fall Time ^{*1}	tf	ID = 8.5 A		6		ns
Total Gate Charge	Qg			10		
Gate to Source Charge	Qgs	VDD = 15 V, VGS = 0 to 4.5 V ID = 8.5 A		3		nC
Gate to Drain Charge	Qgd			4		
Gate resistance	rg	f = 5 MHz		1.2	3	Ω

Body Diode Characteristic

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Diode Forward Voltage	VSD	IS = 8.5 A, VGS = 0 V		0.8	1.2	V

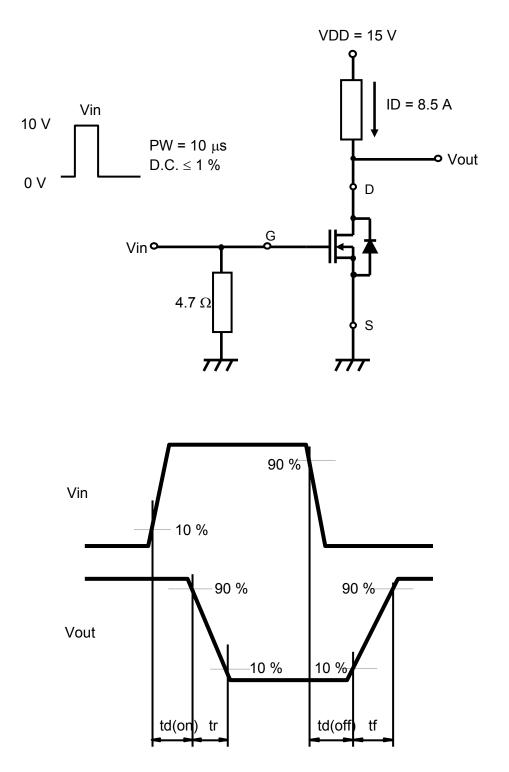
Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

2. *1 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time

Doc No. TT4-EA-14486 Revision. 2



*1 Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time



Established : 2013-01-07 Revised : 2013-05-31 **Panasonic**

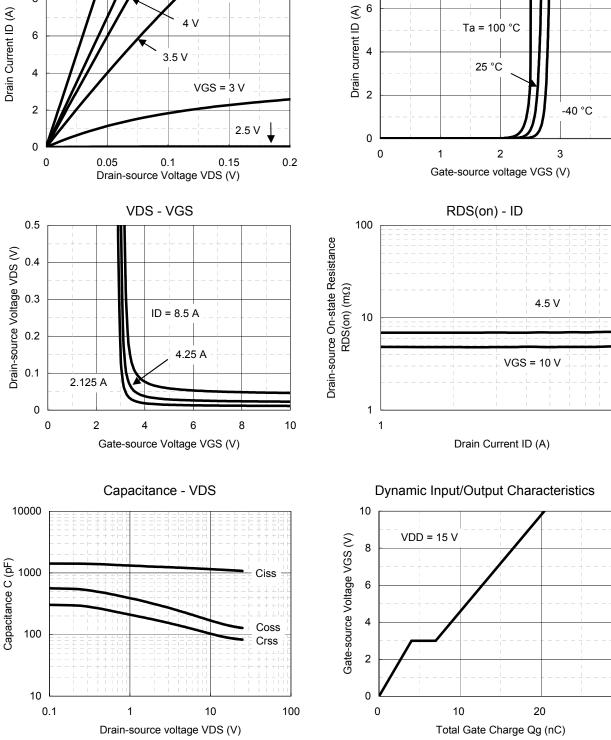
10 V

10

8

ID - VDS

4.5 V



Technical Data (reference)

8

30

10

MOS FET

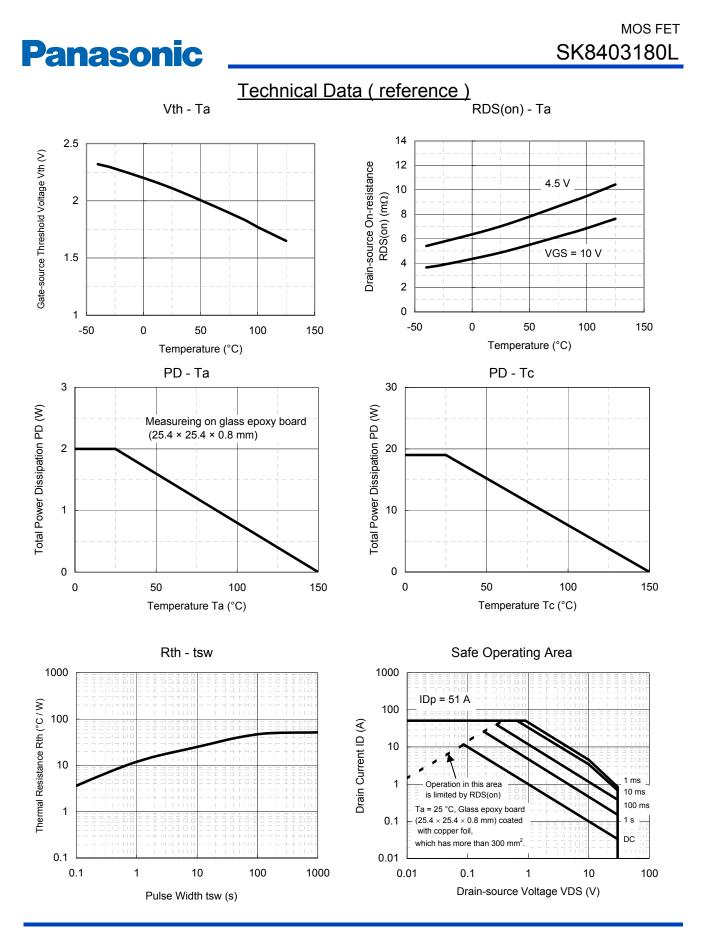
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SK8403180L

ID - VGS

Page 4 of 6

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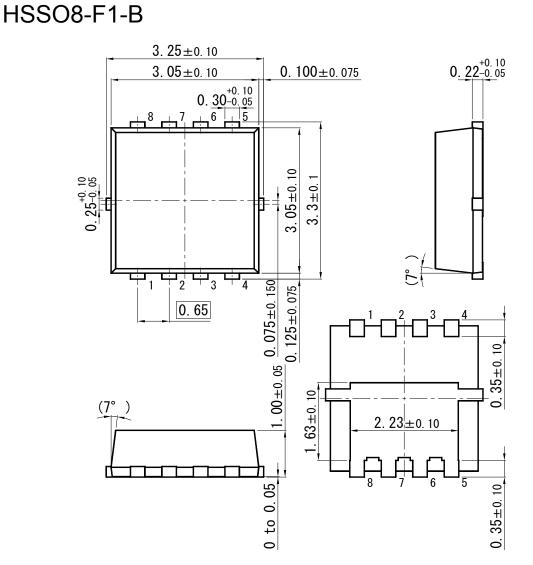


Page 5 of 6

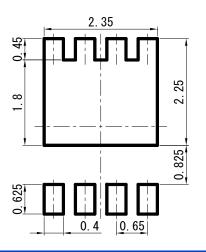
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Unit: mm



Land Pattern (Reference) (Unit : mm)



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